

# 2SJ160, 2SJ161, 2SJ162

Silicon P Channel MOS FET

REJ03G0847-0200 (Previous: ADE-208-1182) Rev.2.00 Sep 07, 2005

### Description

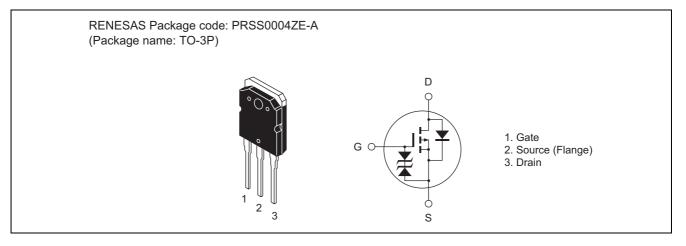
Low frequency power amplifier

Complementary pair with 2SK1056, 2SK1057 and 2SK1058

### Features

- Good frequency characteristic
- High speed switching
- Wide area of safe operation
- Enhancement-mode
- Good complementary characteristics
- Equipped with gate protection diodes
- Suitable for audio power amplifier

### Outline





## **Absolute Maximum Ratings**

				$(1a = 25^{\circ}C)$
Item		Symbol	Value	Unit
Drain to source voltage	2SJ160	V <sub>DSX</sub>	-120	V
	2SJ161		-140	
	2SJ162		-160	
Gate to source voltage		V <sub>GSS</sub>	±15	V
Drain current		ID	-7	А
Body to drain diode reverse drain current		I <sub>DR</sub>	-7	А
Channel dissipation		Pch Note 1	100	W
Channel temperature		Tch	150	٥C
Storage temperature		Tstg	-55 to +150	°C
	20	•	•	

 $(T_{2} - 25^{\circ}C)$ 

Note: 1. Value at  $Tc = 25^{\circ}C$ 

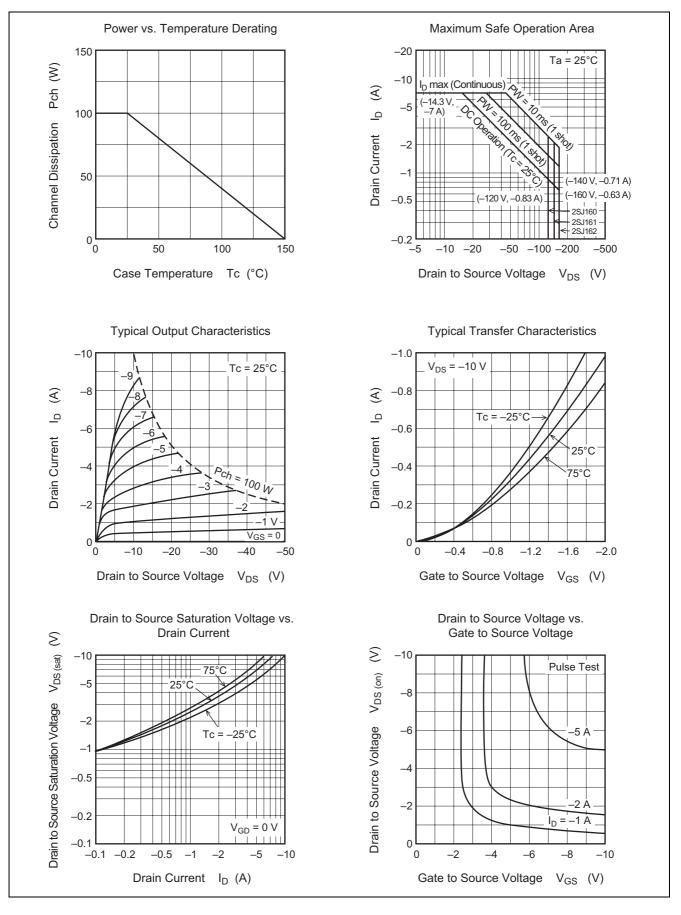
## **Electrical Characteristics**

 $(Ta = 25^{\circ}C)$ Symbol Unit **Test Conditions** Item Min Тур Max  $I_{D} = -10 \text{ mA}, V_{GS} = 10 \text{ V}$ Drain to source breakdown 2SJ160 -120 V V (BR) DSX voltage 2SJ161 -140 V \_ \_ 2SJ162 V -160 \_\_\_\_ \_\_\_\_ Gate to source breakdown voltage V (BR) GSS ±15 V  $I_G=\pm 100~\mu A,~V_{DS}=0$ V  $I_D = -100 \text{ mA}, V_{DS} = -10 \text{ V}$ Gate to source cutoff voltage V<sub>GS (off)</sub> -0.15 \_ -1.45  $I_D = -7 \text{ A}, V_{GS} = 0^{\text{Note 2}}$ Drain to source saturation voltage V<sub>DS (sat)</sub> \_\_\_\_ \_\_\_\_ -12 V  $I_D = -3 \text{ A}, V_{DS} = -10 \text{ V}^{\text{Note 2}}$ S Forward transfer admittance **V**fs 0.7 1.0 1.4  $V_{GS} = 5 V, V_{DS} = -10 V,$ pF Input capacitance Ciss 900 \_\_\_\_ Output capacitance Coss 400 pF f = 1 MHz\_\_\_\_ \_ Reverse transfer capacitance Crss \_\_\_\_ 40 \_\_\_\_ pF t<sub>on</sub>  $V_{DD} = -20 \text{ V} \text{ I}_{D} = -4 \text{ A}$ Turn-on time 230 \_ ns \_\_\_\_ Turn-off time  $t_{\text{off}}$ \_\_\_\_ 110 \_\_\_\_ ns

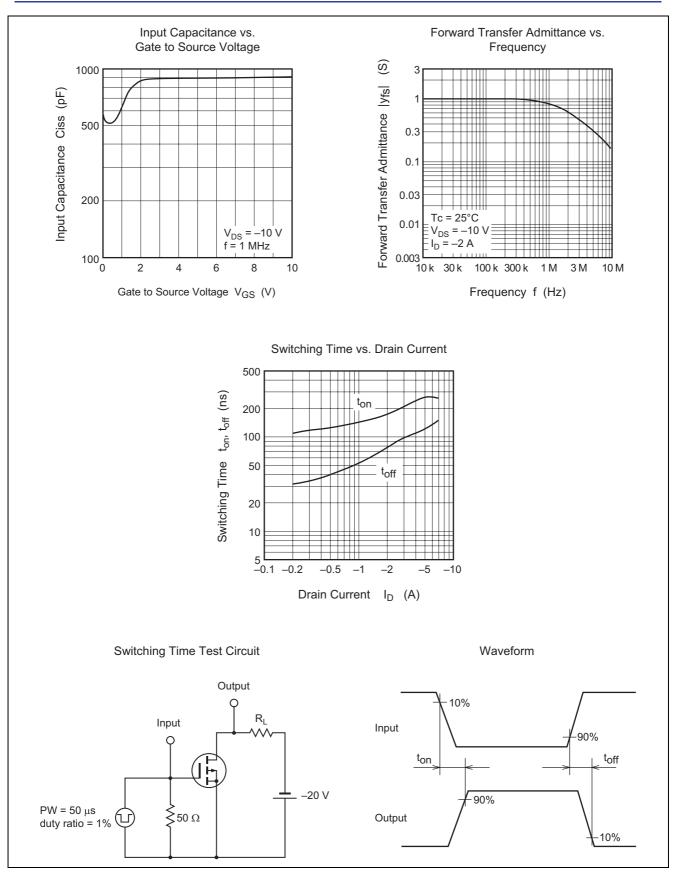
Note: 2. Pulse test



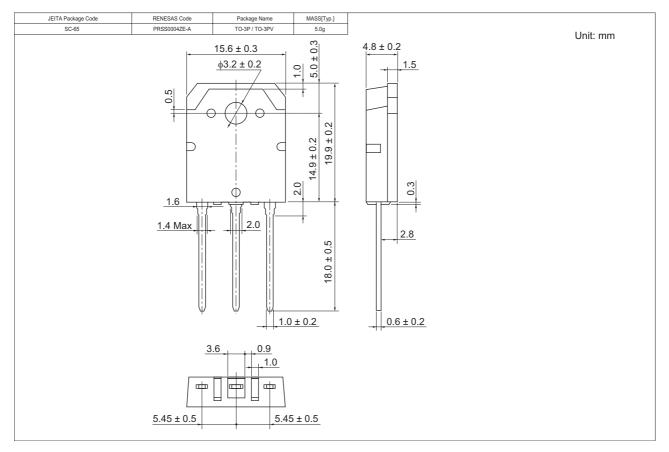
### **Main Characteristics**







### **Package Dimensions**



### **Ordering Information**

Part Name	Quantity	Shipping Container
2SJ160-E	360 pcs	Box (Tube)
2SJ161-E	360 pcs	Box (Tube)
2SJ162-E	360 pcs	Box (Tube)

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.



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